

Gen 4 Silicon Carbide Schottky Diode

Description

This is the 4th generation of high voltage, high performance Z-Rec® silicon carbide Schottky diode in a packageless bare die format to be implemented into any custom module design. The lower forward voltage, smaller reverse leakage current, zero reverse recovery, and high thermal conductivity make this Schottky diode ideal for high frequency switching applications including solar inverter and motor drives. This Schottky diode can be used in conjunction with either IGBT or MOSFET as an anti-parallel diode, or as a rectifier.



Package Type: Bare Die PN's: CPW4-1200-S002B

Features

- 1200V Schottky Rectifier
- Zero Reverse Recovery
- Zero Forward Recovery
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Applications

- Solar Inverters
- Motor Drives
- UPS
- Industrial Power Supplies

Absolute Maximum Ratings

Stress beyond those listed under absolute maximum ratings may damage the device.

Parameter	Symbol		Rating	Unit
Repetitive Peak Reverse Voltage	V_{RRM}		1200	V
Continuous Forward Current	I _F	T _c = 175°C	2	А
Repetitive Peak Forward Surge Current, assumes t _p = 10ms,	I _{FRM}	T _c = 25°C	13	A
Half Sine Wave Pulse	IFRIVI	$T_c = 110^{\circ}C$	8.4	
Non-Repetitive Forward Surge Current, assumes t _p = 10ms,		$T_c = 25^{\circ}C$	19	Ι Λ
Half Sine Wave Pulse	IFSM	T _c = 110°C	16.5	A
Virtual Junction and Storage Temperature	T _{VJ} , T _{stg}		-55 to +175	°C
Maximum Processing Temperature, in non-reactive ambient	T _{proc}		325	°C

Note: All above notation to T_c specifies case temperature from die packaged in TO-247, with Rth(j-c) < 2.5°C/W

Electrical Characteristics (T_{VJ} = 25°C)

Parameter	Symbol	Тур.	Max.	Unit	Test Conditions
Forward Voltage V _f	\	1.4	1.8	.,,	I _F = 2 A
	V _f	V _f	1.9	3	V
Davis and Comment	I _R	10	50	μΑ	V _R = 1200 V
Reverse Current		40	150		V _R = 1200 V, T _{VJ} = 175°C
Total Capacitive Charge	Qc	11		nC	V _R = 800 V, I _F = 2 A, di/dt = 200 A/μs
Total Capacitance	С	167			V _R = 0 V, f = 1Mhz
		11		pF	V _R = 400 V, f = 1Mhz
		8			V _R = 800 V, f = 1Mhz

Thermal Characteristics

Parameter	Symbol	Typical	Unit
Thermal Resistance from Junction to Case ¹	$R_{th(j-c)}$	2.5	°C/W

Note:

¹Tested in TO-247 Package

Typical Performance

All the graphs are based on a die placed in a TO-247 package.

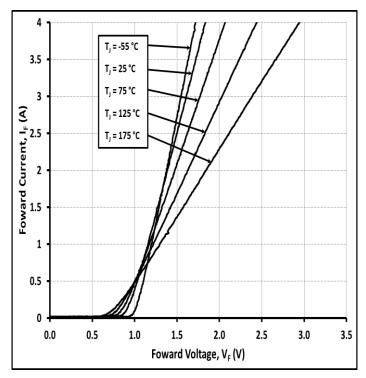


Figure 1.

Typical Forward Characteristics

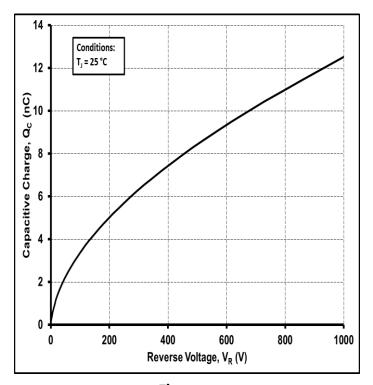


Figure 3.

Typical Capacitance vs Reverse Voltage

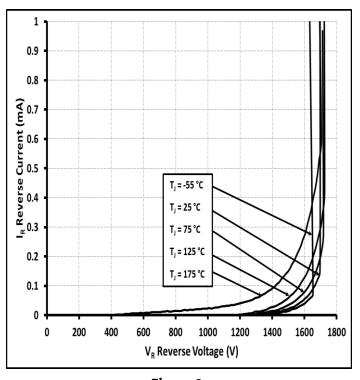


Figure 2.

Typical Reverse Characteristics

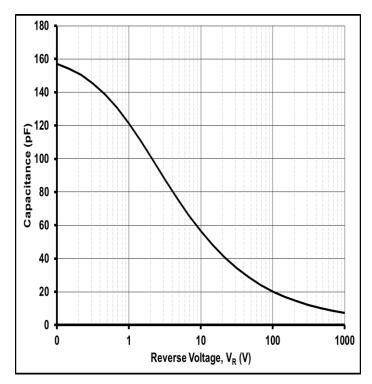
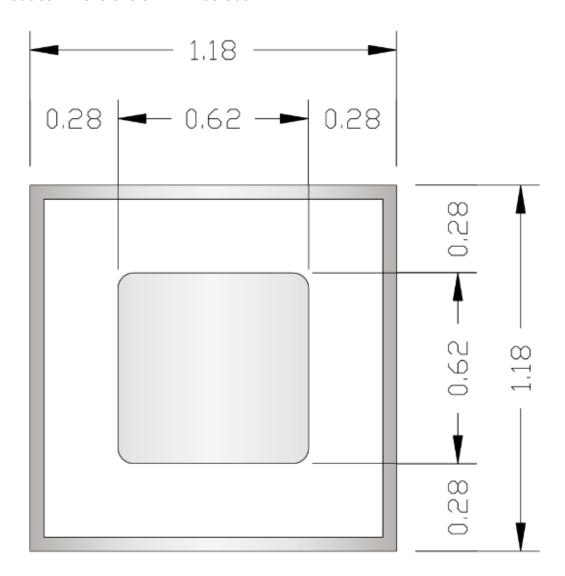


Figure 4.

Typical Recovery Charge vs Reverse Voltage

Product Dimensions CPW4-1200-S002B



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Parameter	Typical	Units
Die Size (L x W)	1.18 x 1.18	mm
Anode Pad Opening	0.62 x 0.62	mm
Die Thickness ¹	377 ± 10%	μm
Topside Anode Metalization (Al)	4	μm
Backside Cathode Metalization (Ni/Ag)	1.8	μm
Frontside Passivation (polymide)	Polyimide	

¹SiC Thickness

Product Ordering Information

Order Number	Description	Package
CPW4-1200-S002B-FU6	SiC Diode G4 IND 1200V/2A FULL MLT	Bare Die Product

Revision History

Revision History	Date of Change	Brief Summary	
2		Initial Release	
3	9/30/2023	Template updated	

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Contact info:

4600 Silicon Drive Durham, NC 27703 USA Tel: +1.919.313.5300 www.wolfspeed.com/power

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